## NSN 5961-00-712-4003

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View Online at https://aerobasegroup.com/nsn/5961-00-712-4003 **Inclosure Material:** Metal **Overall Length:** Between 0.480 inches and 0.510 inches Overall Diameter: Between 0.360 inches and 0.370 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Emitter **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 40.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 2.00 milliamperes source cutoff current and 25.00 microamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release2417 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:** 

No

Demilitarization:

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